



## 2STL1360

### LOW VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

#### Features

- VERY LOW COLLECTOR-EMITTER SATURATION VOLTAGE
- HIGH CURRENT GAIN CHARACTERISTIC
- FAST-SWITCHING SPEED
- IN COMPLIANCE WITH THE 2002/93/EC EUROPEAN DIRECTIVE

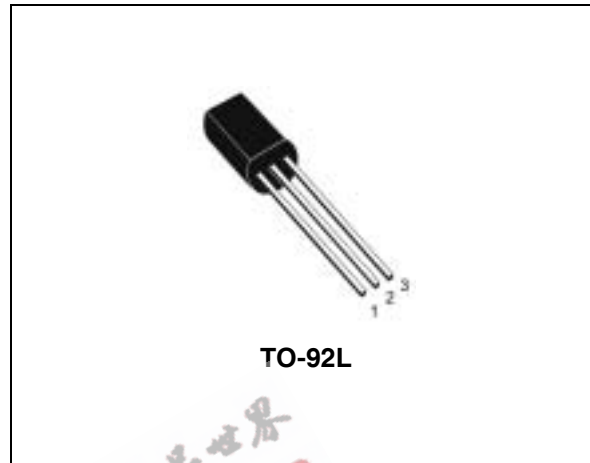
#### Applications

- EMERGENCY LIGHTING
- LED
- CCFL DRIVERS (BACK LIGHTING)
- VOLTAGE REGULATION
- RELAY DRIVER

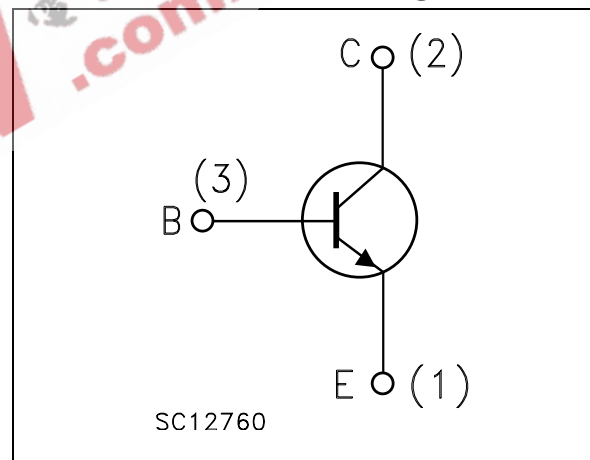
#### Description

The 2STL1360 is a NPN transistor manufactured using new "PB-HDC" (Power Bipolar High Density Current) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

DATA BRIEF



#### Internal Schematic Diagram



#### Order Codes

Part Number	Marking	Package	Packing
2STL1360	L1360	TO-92L	Bulk

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